

ED0757-XX-581

主要参数 MAIN CHARACTERISTICS

$I_{T(AV)}$	12A
V_{DRM}/V_{RRM}	600V
I_{GT}	1-15mA

用途

- 半交流开关
- 相位控制

APPLICATIONS

- Half AC switching
- Phase control

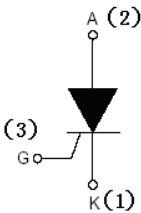
产品特性

- 玻璃钝化芯片，高可靠性和一致性
- 低通态电流和高浪涌电流能力
- 环保 RoHS 产品

FEATURES

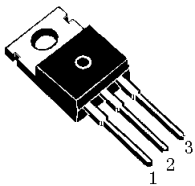
- Glass-passivated mesa chip for reliability and uniform
- Low on-state voltage and High I_{TSM}
- RoHS products

封装 Package



序号 Pin	引线名称 Description	
1	阴极	K
2	阳极	A
3	门极	G

TO-220C



订货信息 ORDER MESSAGE

订 货 型 号 Order codes		印 记 Marking	封 装 Package	器件重量 Device Weight
有卤-条管	有卤-袋装			
Halogen-Tube	Halogen-Reel			
ED0757-XX-581	ED0757-XX-581	ED0757-XX-581	TO-220C	2.15g (typ)



绝对最大额定值 ABSOLUTE RATINGS ($T_c=25^{\circ}\text{C}$)

项 目 Parameter	符 号 Symbol	数 值 Value	单 位 Unit
断态重复峰值电压 Repetitive peak off-state voltage	V_{DRM}	600	V
反向重复峰值电压 Repetitive peak reverse voltage	V_{RRM}	600	V
通态平均电流 Average on-state current (half sine wave)	$I_{\text{T(AV)}}$	12	A
通态方均根电流 On-state RMS current (all conduction angles)	$I_{\text{T(RMS)}}$	18	A
非重复浪涌峰值通态电流 Non- repetitive surge peak on-state current (half sine wave , $t=10\text{ms}$)	I_{TSM}	200	A
I^2t for fusing ($t=10\text{ms}$)	I^2t	200	A^2s
门极峰值电流 Peak gate current	I_{GM}	5	A
门极峰值电压 Peak gate voltage	V_{GM}	5	V
反向门极峰值电压 Peak reverses gate voltage	V_{RGM}	5	V
门极峰值功率 Peak gate power	P_{GM}	20	W
门极平均功率 Average gate power (over any 20ms period)	$P_{\text{G(AV)}}$	0.5	W
存储温度 Storage temperature	T_{stg}	-40~150	$^{\circ}\text{C}$
操作结温 Operation junction temperature	T_{VJ}	125	$^{\circ}\text{C}$



静态特性 STATIC CHARACTERISTICS ($T_C=25^{\circ}\text{C}$ unless otherwise stated)

项 目 Parameter	符号 Symbol	测试条件 Tests conditions	最小 min	典型 typ	最大 max	单位 Unit
断态峰值重复电流 Peak Repetitive Blocking Current	I_{DRM}	$V_{\text{DM}} = V_{\text{DRM}(\text{MAX})}$, $T_j = 125^{\circ}\text{C}$	-	-	1.0	mA
反向峰值重复电流 Peak Repetitive Reverse Current	I_{RRM}	$V_{\text{RM}} = V_{\text{RRM}(\text{MAX})}$, $T_j = 125^{\circ}\text{C}$	-	-	1.0	mA
峰值通态电压 Peak on-state voltage	V_{TM}	$I_{\text{TM}} = 40\text{A}$	-	1.45	1.80	V
门极触发电流 Gate trigger current	I_{GT}	$V_{\text{DM}} = 12\text{V}, I_{\text{T}} = 0.1\text{A}$	1	4	15	mA
门极触发电压 Gate trigger voltage	V_{GT}	$V_{\text{DM}} = 12\text{V}, I_{\text{T}} = 0.1\text{A}$	-	0.8	1.5	V
维持电流 Holding current	I_{H}	$V_{\text{DM}} = 12\text{V}, I_{\text{GT}} = 0.1\text{A}$	-	-	25	mA
擎住电流 Latching current	I_{L}	$V_{\text{DM}} = 12\text{V}, I_{\text{GT}} = 0.1\text{A}$	-	-	40	mA

动态特性 DYNAMIC CHARACTERISTICS ($T_C=25^{\circ}\text{C}$ unless otherwise stated)

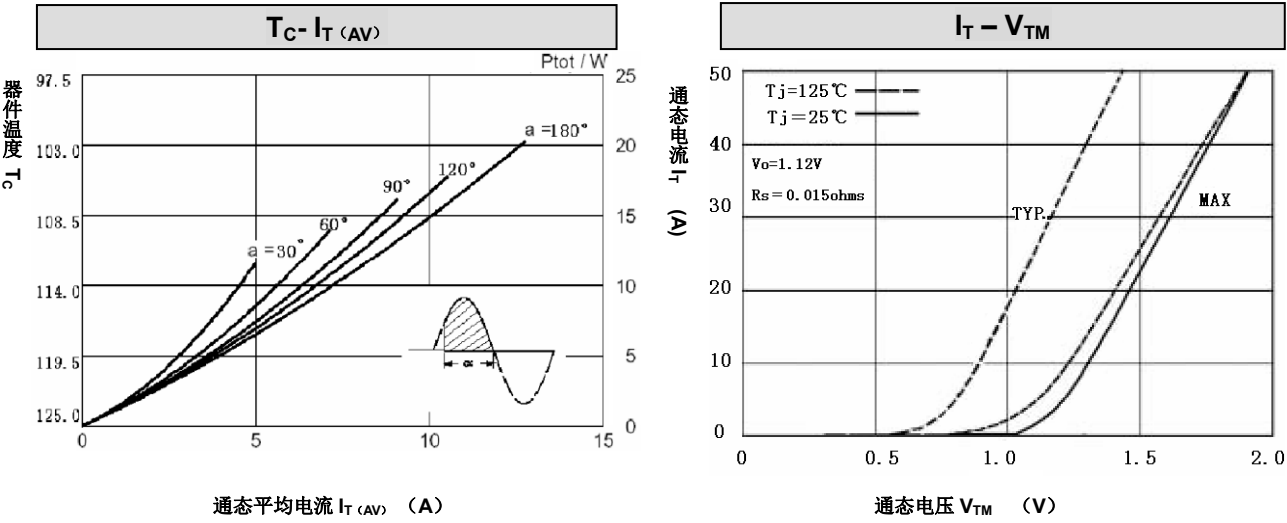
项 目 Parameter	符号 Symbol	测试条件 Tests conditions	最小 min	典型 typ	最大 max	单位 Unit
断态临界电压上升率 Critical rate of rise of off- state voltage	dV/dt	$V_{\text{DM}} = 67\% V_{\text{DRM}(\text{MAX})}$, $T_j = 125^{\circ}\text{C}$	50	200	-	V/ μs

热特性 THERMAL CHARACTERISTIC

项 目 Parameter	符 号 Symbol	值 value	单位 Unit
结到管壳的热阻 Thermal resistance junction to case TO-220C	$R_{\text{th(j-c)}}$	1.1 max	$^{\circ}\text{C/W}$
结到环境的热阻 Thermal resistance junction to ambient	$R_{\text{th(j-a)}}$	60 typ	

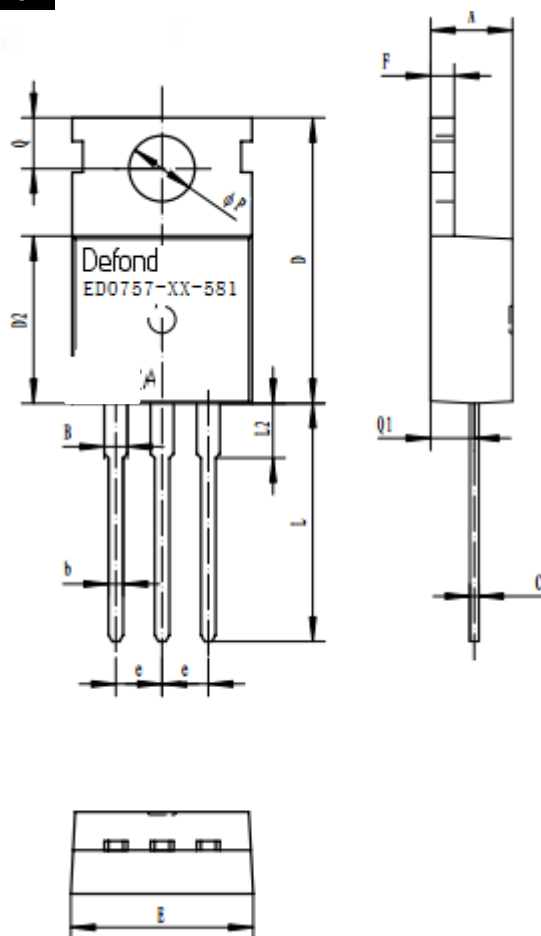


特征曲线 ELECTRICAL CHARACTERISTICS (curves)



外形尺寸 PACKAGE MECHANICAL DATA
TO-220C

单位 Unit : mm



A	4.30-4.70
B	1.22-1.40
b	0.70-0.95
c	0.40-0.65
D	15.2-16.2
D2	9.00-9.40
E	9.70-10.10
e	2.39-2.69
F	1.25-1.40
L	12.60-13.60
L2	2.80-3.20
Q	2.60-3.00
Q1	2.20-2.60
P	3.50-3.80

注意事项

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2. 购买时请认清公司商标，如有疑问请与公司本部联系。
3. 在电路设计时请不要超过器件的绝对最大额定值，否则会影响整机的可靠性。
4. 本说明书如有版本变更不另外告知。

NOTE

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2. We strongly recommend customers check carefully on the trademark when buying our product, if there is any question, please don't be hesitate to contact us.
3. Please do not exceed the absolute maximum ratings of the device when circuit designing.
4. Jilin Sino-microelectronics co., Ltd reserves the right to make changes in this. specification sheet and is subject to change without prior notice.

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